Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

## 2SK2953

## Chopper Regulator, DC-DC Converter and Motor Drive Applications

• Low drain–source ON resistance : RDS (ON) =  $0.31 \Omega$  (typ.) • High forward transfer admittance :  $|Y_{fs}| = 15 S$  (typ.) • Low leakage current : IDSS =  $100 \mu A$  (max) (VDS = 600 V) • Enhancement mode :  $V_{th} = 2.0 \sim 4.0 V$  (VDS = 10 V, ID = 1 mA)

### Absolute Maximum Ratings (Ta = 25°C)

Charac	eteristics	Symbol	Rating	Unit	
Drain-source volta	ge	V <sub>DSS</sub>	600	V	
Drain-gate voltage	e (R <sub>GS</sub> = 20 kΩ)	V <sub>DGR</sub>	600	V	
Gate-source voltage		V <sub>GSS</sub>	±30	V	
Drain current	DC (Note 1)	I <sub>D</sub>	15	TW	
Drain current	Pulse (Note 1)	I <sub>DP</sub>	60	A	
Drain power dissipation (Tc = 25°C)		PD	90	W	
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	1026	mJ	
Avalanche current	Y.CO. TW	I <sub>AR</sub>	15	Α	
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	9	mJ	
Channel temperatu	ire CO	T <sub>ch</sub>	150	.C.∘C	
Storage temperatu	re range	T <sub>stg</sub>	-55~150	°C	

15.8±0.5 Ø3.6±0.2 3.5

2.0 NWW 6

1.0-0.15

1.GATE
2.DRAIN
3.SOURCE

JEDEC —

JEITA —

TOSHIBA 2-16F1B

Weight: 5.8 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

	117			
Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to case	R <sub>th</sub> (ch-c)	1.39	°C/W	
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	41.6	°C/W	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 7.98 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 15 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

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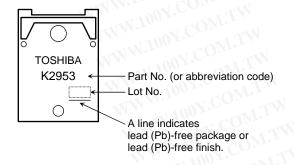
## **Electrical Characteristics (Ta = 25°C)**

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Uni
Gate leakage cu	urrent	I <sub>GSS</sub>	V <sub>GS</sub> = ±25 V, V <sub>DS</sub> = 0 V	TV	_	±10	μΑ
Gate-source br	eakdown voltage	V (BR) GSS	$I_{G} = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_	_	V
Drain cut-off cu	rrent	I <sub>DSS</sub>	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V	M-	- N	100	μΑ
Drain-source br	reakdown voltage	V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	600		_	V
Gate threshold	voltage	$V_{th}$	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0	1	4.0	V
Drain-source O	N resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 8.0 A	~ <del>~</del> M	0.31	0.4	Ω
Forward transfe	r admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 8.0 A	8.0	15.0	_	S
Input capacitano	ce 📉	C <sub>iss</sub>	CONTAIN MANAGE	T.Co.	3520	_	
Reverse transfe	r capacitance	C <sub>rss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	N-CC	20	N —	рF
Output capacita	nce	C <sub>oss</sub>	V.COM. TW WWW.IV	NT.C	300	W.	
OOX.COM	Rise time	Wt <sub>r</sub>	VGS OUT	10 <del>03</del> 1.	50	TY	
Switching time	Turn-on time	ton	V <sub>GS</sub> <sub>0V</sub>	V 100	100	$\frac{M_{\perp}}{M_{\perp}}$	ns
Switching time	Fall time	t <sub>f</sub>	V <sub>DD</sub> = 300V	V <del>I.</del> 10	60	OM.T	
	Turn-off time	t <sub>off</sub>	Duty $\leq 1\%$ , $t_{\mathbf{w}} = 10 \mu s$		325		TV
Total gate charg plus gate-drain)	ge (gate-source )	Qg	WW.100x.COM.TW	NAN	80	¥.€0 <sup>1</sup>	$V_{1}$
Gate-source ch	arge	Q <sub>gs</sub>	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$	W	48	UJ <del>.</del> Cc	nC
Gate-drain ("mi	ller") Charge	Q <sub>gd</sub>	TNW.100 TCOM.	31	32	~ <del>√</del> C	$O_{D_{ij}}$

# Source-Drain Ratings and Characteristics (Ta = 25°C)

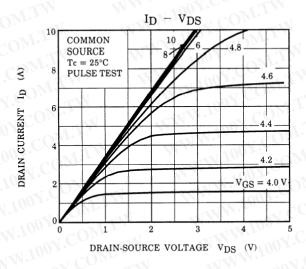
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	WWW.100V.COM	_ WT.		15	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	MMM.1007.COJ	VIIN-	-4	60	A
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 15 A, V <sub>GS</sub> = 0 V	TV+	_ <	-1.7	V
everse recovery time	Ctrr	I <sub>DR</sub> = 15 A, V <sub>GS</sub> = 0 V dI <sub>DR</sub> / dt = 100 A / μs	OM. TA	620	WAN	ns
everse recovery charge	Q <sub>rr</sub>		COM.	7.5	- <del></del>	μC

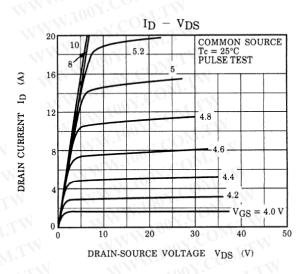
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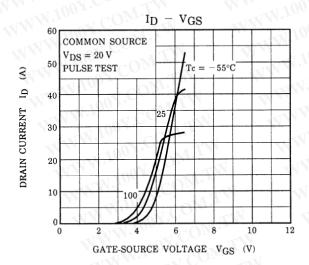


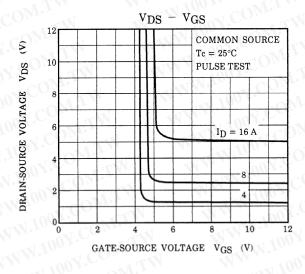
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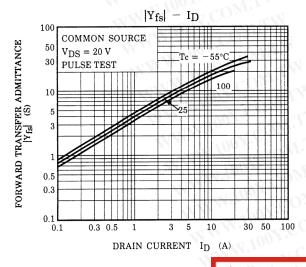
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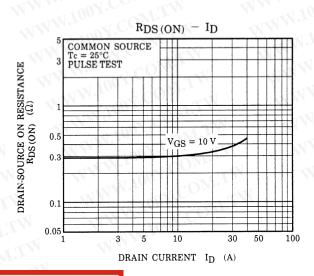








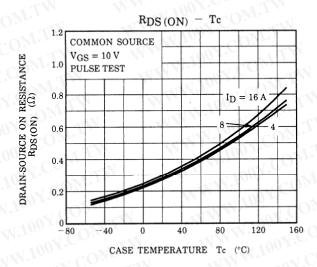


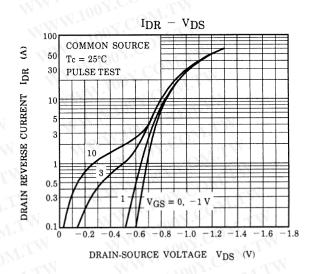


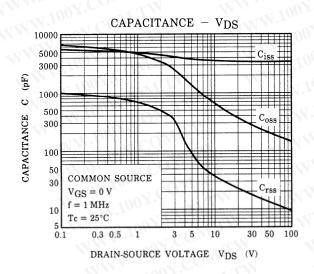
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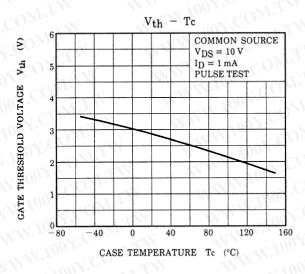
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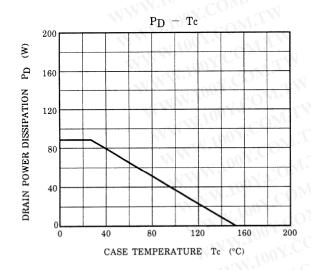
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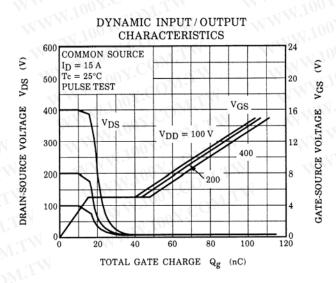




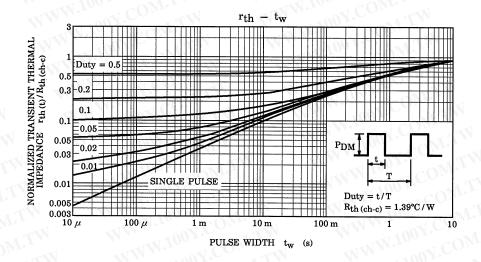


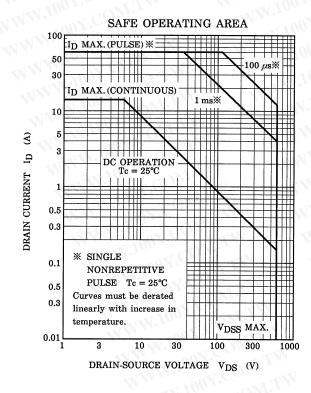


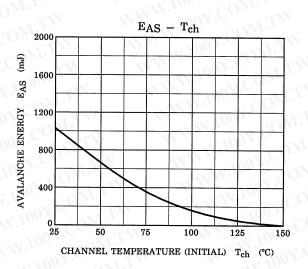


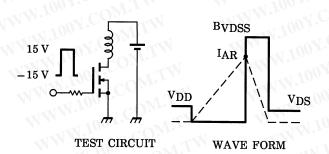


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$$R_G = 25 \Omega$$
  
 $V_{DD} = 90 \text{ V, L} = 7.98 \text{ mH}$ 

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^{2} \cdot \left( \frac{BVDSS}{BVDSS - VDD} \right)$$

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